Semiconductor workflows

Trace contaminant analysis application compendium

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The role of ion chromatography in the semiconductor industry

Demand for semiconductor wafers will continue its vigorous growth as the demand for mobile devices, cloud computing, Internet of Things (IoT), selfdriving automobiles, artificial intelligence, and other uses increases. The complexity of the processes and costs of semiconductor fabrication (FAB) manufacturing are high, so those in the industry are always looking to improve production efficiencies.

lonic contamination is a big concern in semiconductor manufacturing processes, in finished devices, and in consumables such as cleanroom wipes, cotton swabs, gloves, and carriers because small amounts of contamination (parts-per-billion (ppb) to parts-per-million (ppm) concentrations) can cause corrosion, erosion, electromigration, and shorting in devices, on wafers, or in final individual electronic components. Ion chromatography (IC) is an efficient analytical technique that can quickly determine both trace and major constituents of a wide variety of process contaminants in the semiconductor industry. This technique provides a convenient means of quantifying common inorganic anions and cations, certain organic additives, transition metals, polyvalent ions, and organic chelating agents. With online IC process monitoring, these components can be determined quickly at low parts-per-trillion levels to trigger immediate remediation steps.

Process monitoring

Process development

Physical and chemical analysis of semiconductor wafer fab workflows

QA/QC

Failure analysis





Using a reagent-free ion chromatography system to monitor trace anion contamination in the extracts of electronic components

Overview

Keeping the anionic contamination of electronic components low can reduce the incidence of component failure.

The ion chromatography method in Thermo Scientific[™] Application Update 157 (AU157) demonstrated the separation of 14 inorganic anions and organic acids on a Thermo Scientific[™] Dionex[™] IonPac[™] AS17 column set after either a 1 mL direct injection or a 5 mL sample preconcentration.

In this application update, a hydroxide gradient program similar-to, but faster than, the program used in Thermo Scientific[™] Application Note 153 (AN153) separates a new set of 14 anions.

This set of anions differed from the original set by the replacement of nitrite and phthalate with 2-ethylhexanoate and citrate. 2-Ethylhexanoate is the byproduct of an adhesive sometimes used in the disk drive industry.

3.0 -	Peaks:	1. 2. 3. 4. 5. 6. 7. 8. 9. 10.	Fluoride Acetate Formate Acrylate Methacrylate Chloride Unknown 2-Ethylhexanoa Bromide Nitrate Unknown	1.0 5.0 5.0 5.0	0 µg/L 0 0 0 0 75 75 0 5	12. 13. 14. 15. 16. 17. 18. 19. 20. 21. 22.	Benzoate Unknown Carbonate Unknown Sulfate Oxalate Phosphate Unknown Unknown Citrate	- - - 2 2 5 - - 0	5.0 - 1.a. - 2.5 5.0 - - - 0.5
μS/cm			12	4 3 5 6 	10 9 12 7 8 11 	14	17 16 1 15 18	9 20) 22 21
-0.10 0			5	1 10	l 15 Minutes		l 20		 25



Determination of inorganic anions in alkaline solutions

Overview

Trace anions at ppb to ppm concentrations were determined in 100 μ L of concentrated (molar to percent) amine and hydroxide reagent solutions using a single pass autoneutralization step to neutralize the sample.

The neutralized sample was collected and concentrated onto a concentrator column, and finally analyzed by fast anion-exchange chromatography and suppressed conductivity detection.





Determination of trace cations in concentrated acids

Overview

Determination of cations in concentrated acids (24% sulfuric acid, 25% phosphoric acid, and 10% hydrofluoric acid) is important because some cations can combine with anionic contaminants to form insoluble compounds that can cause plating and etching defects in electronics manufacturing processes.

Ion chromatography with suppressed conductivity detection is the preferred method for determining ionic species, especially at µg/L and ng/L concentrations. Direct injection of concentrated acid samples overloads an IC column with the acid cation, resulting in poor chromatography.





Determination of transition metals at ppt levels in high-purity water and SC2 (D-clean) baths

Overview

Metal atoms and conductive particle contaminants are undesirable and potentially damaging in semiconductor manufacturing processes. Oxidative cleaning baths and large volumes of ultrapure rinse water are used to remove metallic contamination from wafer surfaces. For optimal cleaning efficiency, the concentrations of iron and other metals in cleaning solutions should be minimized. To monitor metals in cleaning baths and rinse water, improved analytical methods are needed.

This application note describes a method for determining low ng/L amounts of transition metals in high purity water and semiconductor bath solutions. The Thermo Scientific[™] Dionex[™] IonPac[™] CS5A Column is used for the separation of transition metals. This column has a unique bilayer latex structure consisting of both anion- and cation-exchange retention mechanisms. Transition metals can be separated using either anion or cation exchange chromatography, depending on the choice of the complexing agent used in the eluent.

The figure on the right shows the analysis of 30 mL of a 1 μ g/L transition metals standard. All peaks are well separated from the void volume and from each other and are therefore easily quantified.





Determination of trace anions in high purity waters using a large-volume direct injection

Overview

Trace anion analysis in high purity water is an important application for the semiconductor, disk drive, electronic components, and nuclear power industries. The measurement of trace levels of ionic impurities throughout the power generation process is critical for the identification and prevention of corrosive conditions in many power plant components.

The Thermo Scientific[™] Dionex[™] IonPac[™] AS28-Fast-4µm (2 × 150 mm) Column is well suited for trace-level analysis of common inorganic anions and low molecular weight organic acids. For trace analysis, a large-loop injection combined with gradient elution was used. The column provides improved peak efficiencies compared to the Thermo Scientific[™] Dionex[™] IonPac[™] AS15-5µm (3 × 150 mm) Column, which results in lower detection limits. The Thermo Scientific[™] Dionex[™] ADRS 600 Suppressor delivers low background and noise for sensitivity at trace levels.

The figure on the right shows a typical chromatogram for a standard 11 anions at trace levels. The large peak at ~17 min is carbonate, the size of which will vary with the amount of dissolved carbon dioxide in the sample. The chromatographic baseline shift is approximately 200–300 nS/cm. The separation is performed at 30°C to provide consistent retention times during analysis.

	 Fluoride Acetate Glycolate Formate Chloride Nitrite 	0.125 μg/L 0.313 0.313 0.313 0.313 0.313 0.625	(ppb) 7. 8. 9. 10 1 ⁻ 12	Carbonate Sulfate Oxalate D. Bromide 1. Nitrate 2. Phosphate	0.625 0.313 0.625 0.625 1.250
0.50				7	
µS/cm			6 5	9 ₁₀₁₁	12
0.00	1	2 4 13 10	min ¹⁵	20	25



Determination of silicate in high-purity water using ion chromatography and online sample preparation

Overview

The water used in the manufacture of semiconductors and other modern electronic components must be extremely pure. The production of ultrahighpurity water (UHPW) includes deionization to remove corrosive strong acid anions, e.g., chloride and sulfate. Deionization cartridges exhaust their capacity over time and require replacement. When these deionization cartridges begin to fail, one of the first ions to break through the cartridge and contaminate the water is silicate.

While silicate can be separated at high pH, it has very little dissociation from its acid form at neutral pH, and therefore cannot be detected sensitively using suppressed conductivity. However, silicate will react with molybdate to form a complex that can be detected with high sensitivity at 410 nm.

To confirm that the silicate-free water is indeed silicate-free and can be used to prepare the standards the large loop was filled with the silicate-free water and a blank analysis run. The Thermo Scientific[™] Dionex[™] AutoPrep[™] System was used to calibrate this method. The four standards used by the system for method calibration were 200, 400, 800, and 1,600 ng/L. The figure on the right shows an overlay of these four standards.

This application note shows how the combination of Thermo Scientific[™] Reagent-Free[™] ion chromatography (RFIC[™]) and the Dionex AutoPrep system minimizes the time and labor needed for sensitive and reproducible determinations of silicate in UHPW.





Trace borate determination in high-purity waters

Overview

Borate is one of the most weakly retained anions on anion-exchange materials and is the first to break through many water purification systems. In the power generation and semiconductor industries, monitoring trace levels of boron as borate in high-purity waters is a measure of the efficiency of the water purification systems. The presence of borate is a sign that the water purification system requires service.

In this application note, we demonstrate and evaluate an ion-exclusion method for the determination of trace-level borate in high-purity water. This ionexclusion method coupled with suppressed conductivity detection offers an integrated solution for the determination of trace level boron as borate.

We used a Thermo Scientific[™] Dionex[™] IonPac[™] ICE-Borate analytical column and a Thermo Scientific[™] Dionex[™] IonPac[™] TBC-1 Trace Borate concentrator column, specifically designed for this application. The experimental approach shown combines large sample volume/preconcentration with ion exclusion chromatography. This approach achieves sensitive detection at low to sub-µg/L levels.

View the full application note

The figure below shows a typical chromatogram for a borate standard at trace levels. The typical background conductance ranges from ~140 to 160 μ S/cm depending on the quality of the mannitol used in eluent preparation. The separation is performed at 30°C to provide consistent retention times during analysis specifically (no other anions are concentrated) and can be eluted with an acid/mannitol eluent for the ion exclusion separation step.

This study demonstrated the determination of trace borate in high-purity waters using a large sample volume/preconcentration method with ion-exclusion chromatography and suppressed conductivity detection. The method was validated with calibration and precision studies of deionized (DI) water spiked with trace levels of borate.





Determination of chlorine, bromine, and sulfur in polyethylene materials using combustion ion chromatography

Overview

Polyethylene (PE) is a thermoplastic created from the polymerization of ethylene, a process that produces long, straight chains of hydrocarbon monomers.

Polyethylene is widely used in packaging (plastic bags, plastic films, containers including bottles, etc.).

Plastic materials are not only polymers. Halogen and sulfur containing compounds are often added as plasticizers, flame retardants, and heat stabilizers.

Due to the widespread use of plastic/polymers and their subsequent impact on the environment, it is important to know the content of the halogens and sulfur when polyethylene materials are disposed of or recycled. Combustion ion chromatography allows the analyst to determine the amounts of sulfur and halogens in PE. From the semiconductor and the Institute of Printed Circuits (IPC) industry, halides and sulfur are potentially corrosive and therefore, polymers containing halides and sulfur are avoided by both industries.

Method accuracy was evaluated using a polymer certified reference material (ERM EC680k) for Cl, Br, and S and spike recovery experiments for each analyte.





Measurement and control of copper additives in electroplating baths using high performance liquid chromatography

Overview

The HPLC Corona CAD (Charged Aerosol Detection) methods for the determination of accelerator, leveler, and suppressor organic additives in acid copper plating baths provide reliable and fast determinations of the levels of these organic additives.

Unlike cyclic voltammetric stripping (CVS) analysis that shows a cumulative signal related to all the additives and their impurities, actual quantities of additives can be reliably obtained.

View the full white paper





Airborne molecular contamination clean-room monitoring

Overview

Airborne Molecular Contamination (AMC) is a serious issue in the semiconductor industry as the presence of volatile and semi-volatile organic vapors adversely affects the growth and performance of silicon wafers which in turn affects the performance of microprocessors, data storage devices, and other key electronic components. As such, air cleanliness by chemical concentration (ACC) should be assessed (ISO 14644-8). The contaminants to be monitored as part of ACC are segmented into the following groups:

- Acids
- Bases
- Biotoxics
- Condensables (organic compounds with boiling point (bp) >150°C)
- Corrosives
- Dopants
- Organics (carbon containing compounds)

Thermal desorption coupled to GC or GC-MS is the technique of choice for both online monitoring, with a direct sample analysis after sample collection, and offline monitoring of cleanrooms or material which could outgas and cause AMC, with sample collection separated from sample analysis. For cleanroom monitoring the grade of cleanroom will often determine which type of monitoring is desired, with online measurements being preferred for cleanrooms of a high grade. TD-GC(-MS) can be applied to the measurement of organics, biotoxics, condensables, and dopants from the cleanrooms and from materials.

View the full presentation by Markes International

Airborne molecular contamination (AMC) Clean-Room Monitoring Off-line monitoring of volatile organic contamination in clean-room environments Analysis using Thermal desorption nped sample onto adsorbent tube GC/MS for VVOC. VOC & SVOCs ISO16000-6 Analysis using HPLC -High-performance liquid chromatography ISO16000-3 Pumped sample onto DNPH Cleanroom cartridge for Formaldehyde & Aldehyde

Pin pointing contaminant sources

Condensable and organic contaminants - PCBs

PCBs are emitted from electrical equipment and construction materials.

Organic contamination is important to understand and control because the molecules can adhere onto the surface of silicon wafers leadings irregularities (hydrophobization and haze generation).

This effects clean up of metallic contaminants from the silicon surface and prevents uniform etching of silicon substrates and insulator films during aqueous chemical treatments.

- <u>Sample</u>: 10 ng/µL standard solution of PCBs in isooctane
- Tube and trap: 'SVOC' tube and 'General-purpose' trap



Markes International presentation and images included with permission from Markes International.



Automated industrial manufacturing processed water and wastewater analysis using Thermo Scientific[™] Gallery[™] and Gallery[™] Plus Discrete Analyzer methods

Overview

Most industrial manufacturing processes, such as crude oil distillation, paper production, power generation, and high-speed microprocessor production, require large quantities of high-purity water to avoiding scaling and corrosion, and to maintain component functionality and reliability.

For these industries, accurate monitoring of the quality of raw water intake, process waters, and wastewater are a necessary everyday task.

Gallery and Gallery Plus discrete analyzers are easy-to-use, high-throughput, automated systems that allow laboratories to simplify their testing with dual benefits: time and cost savings. All necessary analysis steps are automated, providing true walkaway time for the operator. Both Gallery and Gallery Plus instruments provide an integrated platform for two measurement techniques, photometric and electrochemical (pH and conductivity), which can be run concurrently. Parallel determination of multiple analytes from a single sample as well as the presence of several automated features ensure analytical efficiency and increase laboratory productivity.

Gallery discrete analyzer – U.S. EPA and international reference methods							
Regulatory methods	Analytes	Regulatory methods	Analytes	Regulatory methods	Analytes		
EPA 310.2 ISBN 0117516015	Alkalinity*	ISO 11083 DIN EN ISO 23913:2009	Hexavalent chromium	EPA 420.1 ISBN 0117516171	Phenols (Total)		
SMWW 2320 B SM 3500-AI B	Aluminium*	ASTM D1687-12(A) SM 3500 Cr-B SW 7196 A		EPA 365.1 EN ISO 6878	Phosphate		
EPA 350.1 ISO 7150 ISO 15923-1	Ammonia	ISO 6332-1988 SM 3500 F-B	Iron	ISBN 0117515825 SM 4500 P-E			
DIN 38406 ISBN 0117516139		SM 3500-Fe B	Iron (Ferrous), Iron (Total)	EPA 365.4 ISBN 0117518883	Phosphorus (Total)		
ISBN 0117515833	Boron*	ASTM D7781-14	Nitrate (TON ENz)	EPA 370.1 ISO 15923-1	Silica		
EPA 410.4	COD*	(NECi) Nitrate					
EPA 325.2	Chloride	drinking water		USGS I-2700-85			
ISO 15923-1 ISBN 0117516260 SM 4500-CI-E		(USGS I-2547-11 (USGS I-2548-11 (NECi) Method N07-0003		EPA 375.4 ISO 15923-1 DIN 38405-D 5-2	Sulfate		
EPA 330.5 SM4500-CI G	Chlorine*	EPA 353.1 ISO 15923-1	Nitrate (TON Hyd)	ASTM D516-11 ISBN 0117533406 SM 4500 SO4-E			
EPA 120.1	Conductivity	ISBN 0117515930 SM 4500-NO3 H		EPA 376.2	Sulfide*		
SM 3500-Cu C	Copper	NEMI (Nitrate via manual	Nitrate (TON Vanadium)	ISBN 011751718			
ASTM D2036-09(B)	Cyanide	Vanadium (III) reduction)		SM 4500-S2 D			
EPA 335.4	Cyanide (Total)	EPA 354.1	Nitrite		Thioovopato*		
EPA 340.3	Fluoride	ISO 13395:1996		510100 4300-CIN-IVI			
EPA 130.1 Hardness (Total)		ISO 15923-1 DIN EN 26777 ISBN 0117515930		ASTM D3590-11 (B) ISBN 0117521299	Nitrogen (TKN)		
rinia party reagents, # a	antor argestion	FPA 150 2	nH	000100 010(01g)			

View the full brochure



Determination of ultratrace elements in semiconductor grade sulfuric acid using the Thermo Scientific[™] iCAP RQ ICP-MS System

Overview

Concentrated sulfuric acid (H_2SO_4) is used in the semiconductor industry to remove organic substances from the surface of silicon wafers. Because H_2SO_4 comes into contact with wafer surfaces, it is necessary to monitor its trace elemental impurities.

High sulfur matrices are problematic in ICP-MS analysis due to the formation of spectral interferences that are preferentially created due to their low ionization energies in the ICP ion source. The most challenging elements in the trace determination of sulfuric acid are Ti, V, Cr, Zn, and Ge. All major isotopes of these metals are severely interfered by polyatomic species generated by the sample matrix.

The iCAP RQ ICP-MS system provides excellent performance in the ultratrace determination of metals in semiconductor grade acid H_2SO_4 . The flexible combination of different analysis modes has been shown to be ideally suited for ultratrace metal determination in advanced semiconductor applications.

	Analyte	Mode	LoD (ng·L⁻¹)	BEC (ng·L⁻¹)	Recovery (%)		
	⁷ Li	CP	0.3	0.9	99		
	²³ Na	CP	0.7	2.6	107		
	²⁴ Mg	CP-NH ₃	0.9	0.8	102		
	²⁷ AI	CP	0.9	1.1	99		
	³⁹ K	CP	2.2	8.5	102		
	⁴⁰Ca	CP	5.9	17.0	103		
	⁴⁸ TiNH(NH ₃) ₃	CCT-Cluster	2.7	21.7	97		
	⁵¹ V	CCT-NH ₃	0.6	0.2	100		
	⁵³Cr	CP-NH ₃	2.7	1.7	103		
	⁵⁵Mn	CP	0.3	0.2	102		
	⁵⁶ Fe	CP	1.0	1.8	100		
	58 Ni	CP	1.5	2.1	98		
	⁵⁹ Co	CP	0.3	0.1	99		
	⁶⁵ Cu	CP	1.9	1.1	103		
	68Zn	KED-NH ₃	0.5	2.9	99		
	⁷¹ Ga	CP	0.1	0.1	101		
	⁷⁴ Ge	KED-NH ₃	0.7	0.1	108		
	^{≈₅} Rb	KED-NH ₃	1.0	0.8	100		
	⁸⁸ Sr	KED-NH ₃	0.5	0.6	105		
	""Cd	KED-He	1.2	0.4	107		
	¹¹⁵ In	KED-He	0.3	0.5	107		
	¹³⁸ Ba	KED-NH ₃	1.1	0.1	96		
	²⁰⁵ TI	KED-He	0.6	0.5	92		
	²⁰⁸ Pb	KED-He	1.5	1.4	97		
	²⁰⁹ Bi	KED-He	0.5	3.1	98		
	²³⁸ U	KED-He	0.4	0.4	101		

Systems solutions

Control of the process steps and wafer environment to meet the daily challenges of routine wafer compliance requires the use of many diverse characterization techniques, including many employing analytical instrumentation.

Learn about semiconductor fabrication and how Thermo Fisher Scientific electron microscopes and analytical instrumentation can help you control process steps and analyze the wafer environment throughout semiconductor manufacturing to ensure you are reaching the highest yield possible.



Thermo Scientific[™] Dionex[™] ICS-6000 HPIC System











Thermo Scientific[™] Gallery[™] and Gallery[™] Plus Discrete Analyzers





Learn more at thermofisher.com/semicon-fab

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